

MES FIELD EFFECT TRANSISTOR

3SK299

RF AMP. FOR UHF TV TUNER N-CHANNEL GaAs DUAL-GATE MES FIFLD-EFFECT TRANSISTOR 4 PIN SMALL MINI MOLD

FEATURES

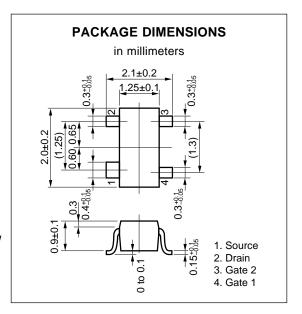
• Suitable for use as RF amplifier in UHF TV tuner.

Low Crss : 0.02 pF TYP.
 High GPS : 20 dB TYP.
 Low NF : 1.1 dB TYP.

• 4 PIN SMALL MINI MOLD PACKAGE

ABSOLUTE MAXIMUM RATINGS (TA = $25 \, ^{\circ}$ C)

Drain to Source Voltage	VDSX	13	V
Gate1 to Source Voltage	V _{G1S}	-4.5	V
Gate2 to Source Voltage	V _{G2} S	-4.5	V
Drain Current	lD	40	mΑ
Total Power Dissipation	Рт	120	mW
Channel Temperature	Tch	125	°C
Storage Temperature	Tstg	-55 to +125	°C



ELECTRICAL CHARACTERISTICS (TA = 25 °C)

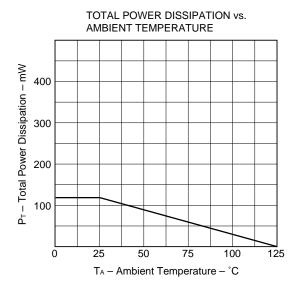
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Drain Current	IDSX			10	μΑ	VDS = 13 V, VG1S = -4 V, VG2S = 0	
Drain Current	IDSS	5	20	40	mA	VDS = 5 V, VG2S = 0, VG1S = 0	
Gate1 to Source Cutoff Voltage	V _{G1S(off)}			-3.5	V	$V_{DS} = 5 \text{ V}, V_{G2S} = 0 \text{ , ID} = 100 \ \mu\text{A}$	
Gate2 to Source Cutoff Voltage	V _{G2S(off)}			-3.5	V	$V_{DS} = 5 \text{ V}, V_{G1S} = 0, I_{D} = 100 \mu A$	
Gate1 Reverse Current	I _{G1SS}			10	μΑ	VDS = 0, VG1S = -4 V, VG2S = 0	
Gate2 Reverse Current	I _{G2} SS			10	μΑ	VDS = 0, VG2S = -4 V, VG1S = 0	
Forward Transfer Admittance	yfs	18	25	35	ms	V _{DS} = 5 V, V _{G2S} = 1 V, I _D = 10 mA f = 1.0 kHz	
Input Capacitance	Ciss	0.5	1.0	1.5	pF	VDS = 5 V, VG2S = 1 V, ID = 10 mA	
Reverse Transfer Capacitance	Crss		0.02	0.03	pF	f = 1 MHz	
Power Gain	GPS	16.0	20.0		dB	VDS = 5 V, VG2S = 1 V, ID = 10 mA	
Noise Figure	NF		1.1	2.5	dB	f = 900 MHz	

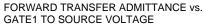
IDSS Classification

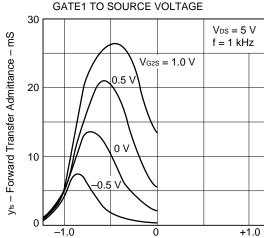
Unit: mA

Class	U71	U72	U73	U74	
Marking	U71	U72	U73	U74	
IDSS	5 to 15	10 to 25	20 to 35	30 to 40	

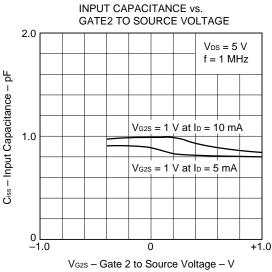
TYPICAL CHARACTERISTICS (TA = 25 °C)



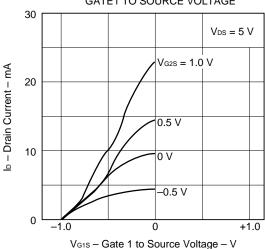


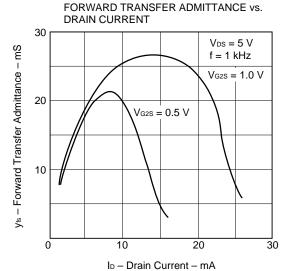


V_{G1S} - Gate 1 to Source Voltage - V

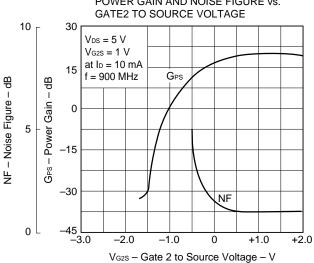


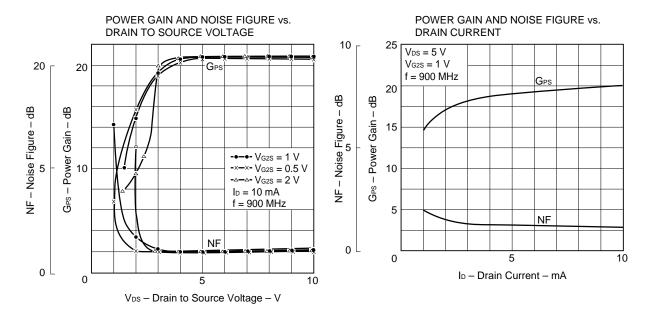
DRAIN CURRENT vs. GATE1 TO SOURCE VOLTAGE





POWER GAIN AND NOISE FIGURE vs.



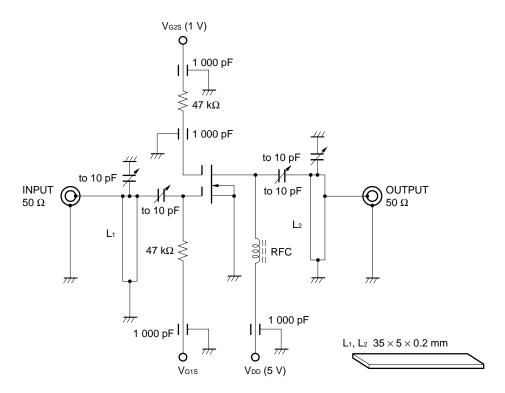


S-PARAMETER (VDS = 5 V, V_{G2S} = 1 V, I_D = 10 mA)

FREQUENCY	S	11	S	521	S	12	s	22
MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100.0000	0.999	-3.3	2.359	177.2	0.006	-122.3	0.969	-1.3
200.0000	1.000	-7.2	2.389	169.3	0.004	123.0	0.981	-2.9
300.0000	0.998	-9.3	2.313	164.4	0.000	-145.0	0.979	-3.3
400.0000	0.974	-13.4	2.233	160.0	0.004	79.2	0.967	5.6
500.0000	1.005	-15.7	2.420	158.4	0.007	29.7	0.999	-5.8
600.0000	0.942	-19.1	2.300	150.0	0.003	65.0	0.958	-7.7
700.0000	0.968	-22.2	2.332	145.5	0.004	45.5	0.997	-8.5
800.0000	0.920	-25.2	2.229	141.5	0.008	80.1	0 957	-9.4
900.0000	0.952	28.9	2.447	136.8	0.004	8.3	0.999	-12.5
1000.0000	0.898	-29.4	2.303	131.1	0.001	50.9	0.968	-11.1
1100.0000	0.915	-35.1	2.348	125.8	0.004	71.4	0.984	-14.8
1200.0000	0.879	-35.2	2.367	123.5	0.000	91.1	0.989	-13.0

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900 MHz GPS AND NF TEST CIRCUIT



 $V_{DS} = 5 \text{ V}, V_{G2S} = 1 \text{ V}, I_{D} = 10 \text{ mA}$

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Anti-radioactive design is not implemented in this product.

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